

Microsemi

Power Matters[™]

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Overview Diagrams

Electrical Rating Symbol Min Typ Max Unit

DC Current Gain HFE 100.00 300.00

Maximum Electrical Rating	Symbol	Min	Тур	Max	Unit
Collector Current (dc)	Ic			0.50	А
Collector-Emitter Voltage (Base Open)	V _{CEO}			80.00	V
Junction Temperature (°C)	T_J			200.00	°C

This part can be found in the following product categories:

- ▶ Non-Radiation Hardened Devices ▶ Transistors ▶ BJT(BiPolar Junction Transistor) ▶ PNP Transistor
- Discretes ▶ Transistors ▶ BJT(BiPolar Junction Transistor) ▶ PNP Transistor

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